

Electronic Acknowledgement Receipt

EFS ID:	3095847
Application Number:	10782017
International Application Number:	
Confirmation Number:	7331
Title of Invention:	Solution-based fabrication of photovoltaic cell
First Named Inventor/Applicant Name:	Dong Yu
Customer Number:	27652
Filer:	Hao Y. Tung
Filer Authorized By:	
Attorney Docket Number:	NSL-029
Receipt Date:	02-APR-2008
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Application Type:	Utility under 35 USC 111(a)

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Submitted with Payment	yes
Payment Type	Credit Card
Payment was successfully received in RAM	\$ 180
RAM confirmation Number	4539
Deposit Account	
Authorized User	

File Listing:

Document Number	Document Description	File Name	File Size(Bytes) /Message Digest	Multi Part /.zip	Pages (if appl.)

1	Information Disclosure Statement (IDS) Filed	NSL-029_IDS_040208.pdf	128469 43bc8554a39496e8553b0a91ab24aec 2a124e0c4	no	7
Warnings:					
Information:					
This is not an USPTO supplied IDS fillable form					
2	Foreign Reference	refAR_DE2741954.pdf	140507 77cea444c76df2aa0a0f79124d480d07 d6da457b	no	7
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3	Foreign Reference	refAS_EP793277.pdf	3321900 5dc819cd3417345670870fa21205e4f3 009d0c5b	no	58
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5	Foreign Reference	refAU_JP63-249379.pdf	156583 bf0f1d84f5e5f89d24a790818cf427ffd71 214d4	no	4
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6	Foreign Reference	refAV_WO02084708.pdf	1573778 fb64c8ac35d8745f64be6e0f7933ddff88 d30ed8	no	50
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7	Foreign Reference	refAW_WO03007386.pdf	833367 1ec5c8e022167f03de325bec2cb4fef3bf a11a58	no	18
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9	NPL Documents	Ref_AY_Non-vacuum-processing.PDF	362877 bfb440a3eb8c46de231f07a7a6edf773d eda9576	no	5

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10	NPL Documents	Ref_AZ_Thin-film-copper-indium-prepared-by-selenization.PDF	861480 9fb6b79d28fc9f8ce1b16a5c9f28e2232 7bd1618	no	12
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11	NPL Documents	Ref_BA_Non-vacuum-processing-of-CIGS-solar-cells.PDF	221351 325434318a623427ab07b9a4a57f43e1 4182230a	no	2
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12	NPL Documents	Ref_BB_CuInSe2-films-prepared-by-screen-printing-and-sintering-method.PDF	375611 72998dd2296016eeddc6661d6979527 0079bfe1	no	6
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13	NPL Documents	Ref_BC_Cu-In-Ga-Se-nanoparticle-colloids-as-spray-deposition-precursors.PDF	486476 6829ee63990a702a1d527c1d5cd0346 c313bc33c	no	5
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16	NPL Documents	Ref_BF_CIS-film-growth-by-metallic-ink-coating-and-selenization.PDF	485589 bc6271841909f81865514f07bca407c5 886684e2	no	8
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22	NPL Documents	Ref_BL_Electrodeposited-CuInSe2-thin-film-junctions.PDF	522093 7e6b859c108c3eccd0017e575f609f68e d26d161	no	11
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23	NPL Documents	Ref_BM_Photoacoustic-spectroscopy-of-sprayed.PDF	233594 d8d113bfac06070501c204ad0499d809 123fb18f	no	3
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25	NPL Documents	Ref_BO_Electrodeposition-and-characterisation-of-CuInSe2.PDF	449095 3e03bc1d9ba5413bcddbbce92ad4fdf 795ca20c	no	6
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27	NPL Documents	Ref_BQ_Planarization-of-copper-thin-by-electropolishing.PDF	642034 e00b8aad73e2db8bef77da9b430691368 0259b7ed	no	5

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32	NPL Documents	Ref_BV_Junction-formation-studies-of-one-step-electrodeposited-CuInSe2.PDF	660234 255b8afed173f205c0057c249cbd8d81c 2e1015d	no	6
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38	NPL Documents	REF_CC_metastable.pdf	275418 998085a462384718e62d6f7cd919cd3b78c580c0	no	4
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39	NPL Documents	REF_CE_TEM_observations.pdf	557592 d27e234abeb987f0e18ff27ec922975ecd4c4ef	no	6
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40	NPL Documents	REF_CF_gallium_droplet_for mation_during_movepe.pdf	97700 18055e3eaa2719a3e80be41b600f8491 248708a3	no	3
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46	Fee Worksheet (PTO-06)	fee-info.pdf	8147 f1151f691b6764eboda82d931f48baa15 b7d81e4	no	2
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			Total Files Size (in bytes):	35274152	
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